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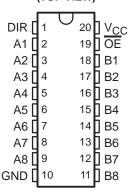
- **EPIC™** (Enhanced-Performance Implanted **CMOS) Process**
- Inputs Are TTL-Voltage Compatible
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- **Package Options Include Plastic** Small-Outline (DW), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) DIPs

description

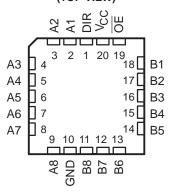
These octal bus transceivers are designed for asynchronous two-way communication between data buses. The control-function implementation minimizes external timing requirements.

The 'AHCT245 devices allow data transmission from the Abus to the Bbus or from the Bbus to the A bus, depending upon the logic level at the direction-control (DIR) input. The output-enable (OE) input can be used to disable the device so that the buses are effectively isolated.

SN54AHCT245 . . . J OR W PACKAGE SN74AHCT245...DB, DGV, DW, N, OR PW PACKAGE (TOP VIEW)



SN54AHCT245 . . . FK PACKAGE (TOP VIEW)



To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54AHCT245 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74AHCT245 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE (each transceiver)

INP	UTS	OPERATION					
OE	DIR	OPERATION					
L	L	B data to A bus					
L	Н	A data to B bus					
Н	X	Isolation					

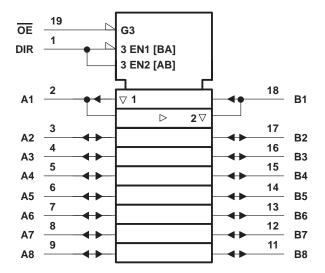


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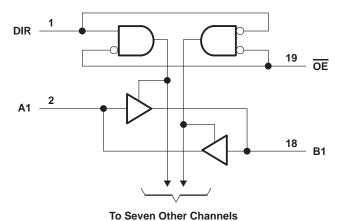


logic symbol†



 $[\]ensuremath{^{\dagger}}$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}		–0.5 V to 7 V
Input voltage range, V _I (see Note 1)		0.5 V to 7 V
Output voltage range, VO (see Note 1)		–0.5 V to V _{CC} + 0.5 V
Input clamp current, $I_{ K }(V_{ I } < 0)$		–20 mA
Output clamp current, IOK (VO < 0 or VO > VCO	c)	±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	· · · · · · · · · · · · · · · · · · ·	±25 mA
Continuous current through V _{CC} or GND		±75 mA
Package thermal impedance, θ _{JA} (see Note 2):	: DB package	70°C/W
	DGV package	92°C/W
	DW package	58°C/W
	N package	69°C/W
	PW package	83°C/W
Storage temperature range, T _{stg}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 3)

		SN54AH	CT245	SN74AH	UNIT	
		MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2		2		V
V _{IL}	Low-level input voltage		0.8		0.8	V
VI	Input voltage	0	5.5	0	5.5	V
VO	Output voltage	0	Vcc	0	VCC	V
IOH	High-level output current		-8		-8	mA
loL	Low-level output current		8		8	mA
Δt/Δν	Input transition rise or fall rate		20		20	ns/V
TA	Operating free-air temperature	-55	125	-40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	Vaa	T,	չ = 25°0	;	SN54AHCT245		SN74AHCT245		UNIT
		TEST CONDITIONS	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
VOH		I _{OH} = -50 μA	4.5 V	4.4	4.5		4.4		4.4		V
		$I_{OH} = -8 \text{ mA}$	4.5 V	3.94			3.8		3.8		V
\/a:		I _{OL} = 50 μA	4.5 V			0.1		0.1		0.1	V
VOL		I _{OL} = 8 mA	4.5 V		0.3		0.44		0.44		V
II	OE or DIR	$V_I = V_{CC}$ or GND	0 V to 5.5 V			±0.1		±1*		±1	μΑ
loz	A or B inputs†	$V_O = V_{CC}$ or GND	5.5 V			±0.25		±2.5		±2.5	μΑ
ICC		$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μΑ
ΔlCC [‡]		One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V		·	1.35		1.5		1.5	mA
Ci	OE or DIR	$V_I = V_{CC}$ or GND	5 V		2.5	10				10	pF
Cio	A or B inputs	$V_I = V_{CC}$ or GND	5 V		4						pF

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0 \text{ V}$.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	TA	√ = 25°0)	SN54Al	1CT245	SN74AH	CT245	UNIT		
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT		
^t PLH	A or B	B or A	C _L = 15 pF		4.5**	7.7**	1**	10**	1	8.5	ns		
^t PHL	AUD	DUIA	CL = 15 pr		4.5**	7.7**	1**	10**	1	8.5	115		
^t PZH	ŌĒ	A or B	C _I = 15 pF		8.9**	13.8**	1**	16**	1	15	20		
^t PZL	OE	AUID	CL = 15 pr		8.9**	13.8**	1**	16**	1	15	15 ns		
^t PHZ	ŌĒ	A or B	C _I = 15 pF		9.2**	14.4**	1**	16.5**	1	15.5	ns		
t _{PLZ}		OE	OE	OE	AOID	OL = 13 pr		9.2**	14.4**	1**	16.5**	1	15.5
tPLH	A - : : D	A or B	B or A	C: 50 pF		5.3	8.7	1	11	1	9.5	20	
t _{PHL}	AUD	D OI A	C _L = 50 pF		5.3	8.7	1	11	1	9.5	ns		
^t PZH		A D	C 50 pF		9.7	14.8	1	17	1	16	ns		
t _{PZL}	OE A OF B	OE	OE A or B	$C_L = 50 pF$		9.7	14.8	1	17	1	16	IIS	
^t PHZ	ŌĒ	A or B	C _I = 50 pF		10	15.4	1	17.5	1	16.5	no		
tPLZ		AUID	OL = 30 pr		10	15.4	1	17.5	1	16.5	ns		
t _{sk(o)}			C _L = 50 pF			1***				1	ns		

^{**} On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics, V_{CC} = 5 V, C_L = 50 pF, T_A = 25°C (see Note 4)

	PARAMETER	SN74AHCT245			UNIT
	MIN	TYP	MAX	ONIT	
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		4		V
V _{IH(D)}	High-level dynamic input voltage	2			V
V _{IL(D)}	Low-level dynamic input voltage			0.8	V

NOTE 4: Characteristics are for surface-mount packages only.



[†] For I/O ports, the parameter IOZ includes the input leakage current.

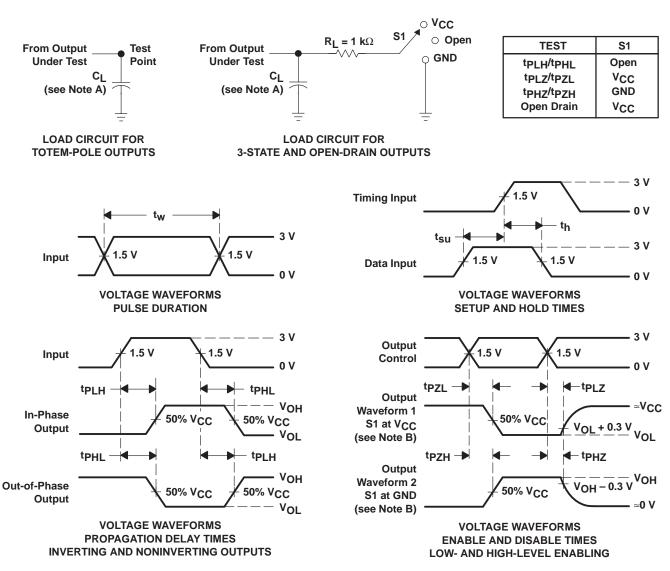
[‡]This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or VCC.

^{***} On products compliant to MIL-PRF-38535, this parameter does not apply.

operating characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER			ONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load,	f = 1 MHz	13	pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , $t_f \leq$ 3 ns, $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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